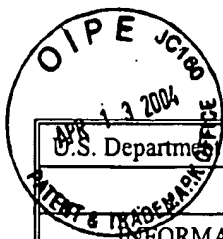


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				M-12200-1D US		Unassigned <u>10/658934</u>		
INFORMATION DISCLOSURE STATEMENT BY APPLICANT				Applicant(s)				
(Use several sheets if necessary)				Chia-Shun Hsiao				
				Filing Date		Group		
				Herewith		Unassigned		
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Examiner <u>ANH D. MAI</u>		Date Considered <u>11/16/04</u>						
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(Use several sheets if necessary)				Chia-Shun Hsiao				
				Filing Date		Group		
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							Translation	
		Document	Date	Country	Class	Subclass	Yes	No
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Examiner		ANH D. MAI		Date Considered		11/16/04		
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					Filing Date		Group	
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							Yes	No
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